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Journal Information

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Classification History

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2026		✓	✓	
2025		✓	✓	
2024		✓	✓	
2023		✓	✓	
2021/2022		✓	✓	
2020		✓	✓	
2019		✓	✓	
2018		✓		

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Authors: Rajababu Chintaparty
DOI: 10.1149/2162-8777/aebcb5

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2026-11-2
Authors: Yu Xiang Wang, Jui-Hung Lin, YI CHENG WANG et al.
DOI: 10.1149/2162-8777/aebcb4

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2026-10-28
Authors: Neng-Da Li, Yueh-Chin Lin, Howie Tseng et al.
DOI: 10.1149/2162-8777/aebabd

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2026-10-23
Authors: Haley E Dishman, Sujitra Pookpanratana, Owen R Meilander et al.
DOI: 10.1149/2162-8777/aeb8f5

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2026-10-23
Authors: Nils Donker, Jens Zosel, Ralf Moos et al.
DOI: 10.1149/2162-8777/aeb869

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DOI: 10.1149/2162-8777/aeb721

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2026-10-16
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DOI: 10.1149/2162-8777/aeb572

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DOI: 10.1149/2162-8777/aeac85

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Authors: Hoang-Tan-Ngoc Nguyen, Rahul Rai, Duy-Hung Tran et al.
DOI: 10.1149/2162-8777/aeb15e

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Authors: Chien-Hung Ko, Ching-Sung Lee, Ching-Huan Peng et al.
DOI: 10.1149/2162-8777/aeb571